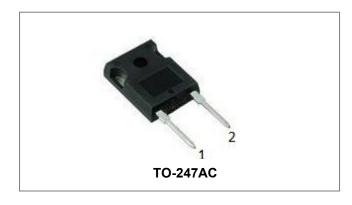


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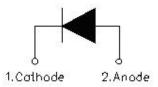
## SDUR3030W ULTRAFAST RECTIFIER



# **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### **Circuit Diagram**



#### **Features**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	300	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=105°C, rectangular wave form	30	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	250	А

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 30A, Pulse, T <sub>J</sub> = 25°C	1.28	1.3	V
	$V_{F2}$	@ 30A, Pulse, T <sub>J</sub> = 125°C	1.22	1.25	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R$ $T_J = 25$ °C	0.3	5.0	μΑ
	I <sub>R2</sub>	$@V_R = rated V_R$ $T_J = 125^{\circ}C$	40	1.0	mA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>rm</sub> =250mA	40	45	ns

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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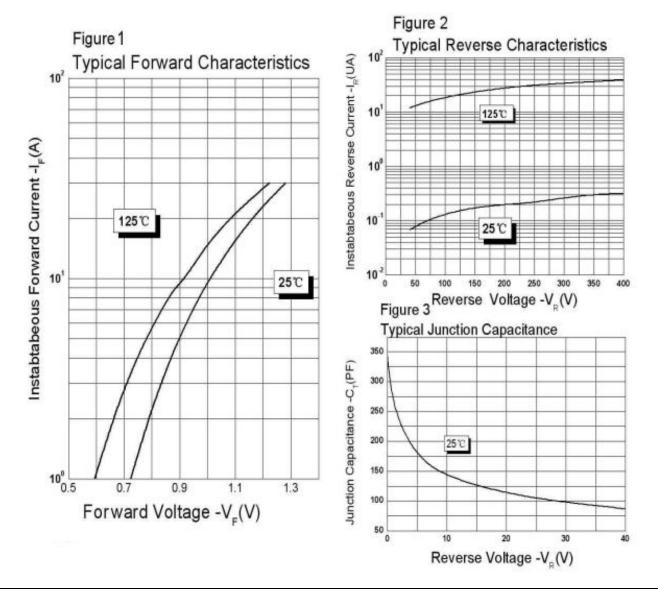




## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	4	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

### **Ratings and Characteristics Curves**



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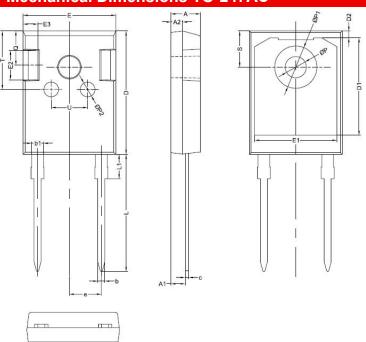


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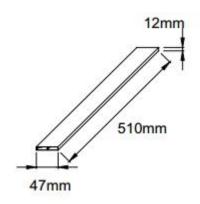
### **Mechanical Dimensions TO-247AC**



CVMPOL	Millimeters					
SYMBOL	MIN.	TYP.	MAX.			
Α	4.80	5.00	5.20			
A1	2.20	2.41	2.61			
A2	1.90	2.00	2.10			
b	1.10	1.20	1.35			
b1	1.80	2.00	2.20			
С	0.50	0.60	0.75			
D	20.30	21.00	21.20			
D1 D2		16.58				
D2		1.17				
Ε	15.60	15.80	16.00			
E1		14.02				
E2		5.00				
E3		2.50				
е		5.44				
L	19.42	19.92	20.42			
L1		4.13				
Р	3.50	3.60	3.70			
P1	7.1	7.19	7.40			
P2		2.50				
Q		5.80				
Q S	6.05	6.15	6.25			
T		10.00				
U		6.20				

Note: Date code is after 17501, please use this new TO-247AC mechanical dimensions.

### **Tube Specification**



### **Marking Diagram**



Where XXXXX is YYWWL

 SDUR
 = Device Type

 30
 = Forward Current (30A)

 30
 = Reverse Voltage (300V)

 W
 = Configuration

 SSG
 = SSG

 YY
 = Year

WW = Week L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

### **Ordering Information**

Device	Package	Shipping	
SDUR3030W	TO-247AC(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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#### **SDUR3030W**



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